

### Fast switching diode

### Features:

- 600V Emitter Controlled technology 70 µm chip
- soft , fast switching
- low reverse recovery charge
- small temperature coefficient

### This chip is used for:

• power modules and discrete devices



### Applications:

 SMPS, resonant applications, drives

Chip Type	V <sub>R</sub>	I <sub>F</sub>	Die Size	Package
SIDC09D60F6	600V	30A	3 x 3 mm <sup>2</sup>	sawn on foil

### **Mechanical Parameters**

Raster size	3 x 3		
Area total	9	mm <sup>2</sup>	
Anode pad size	2.518 x 2.518		
Thickness	70	μm	
Wafer size	150	mm	
Max. possible chips per wafer	1667		
Passivation frontside Photoimide			
Pad metal	3200 nm AlSiCu		
Backside metal	Ni Ag –system suitable for epoxy and soft solder die bonding		
Die bond	Electrically conductive glue or solder		
Wire bond AI, ≤250µm			
Reject ink dot size	Ø 0.65mm; max 1.2mm		
Recommended storage environment	Store in original container, in dry nitrogen, in dark environment, < 6 month at an ambient temperature of 23°C		



### **Maximum Ratings**

Parameter	Symbol	Condition	Value	Unit
Repetitive peak reverse voltage	V <sub>RRM</sub>	<i>T</i> <sub>vj</sub> = 25 °C	600	V
Continuous forward current	1 <sub>F</sub>	<i>T</i> <sub>vj</sub> < 150°C	1)	•
Maximum repetitive forward current	I <sub>FRM</sub>	<i>T</i> <sub>vj</sub> < 150°C	60	A
Junction temperature range	T <sub>vj</sub>		-40+175	°C
Operating junction temperature	T <sub>vj</sub>		-40+150	°C
Dynamic ruggedness <sup>2)</sup>	P <sub>max</sub>	$I_{\rm Fmax}$ = 60A, $V_{\rm Rmax}$ = 600V, $T_{\rm vj} \le 150^{\circ}{\rm C}$	tbd	kW

<sup>1</sup>) depending on thermal properties of assembly

<sup>2</sup>) not subject to production test - verified by design/characterisation

### Static Characteristic (tested on wafer), T<sub>vj</sub> = 25 °C

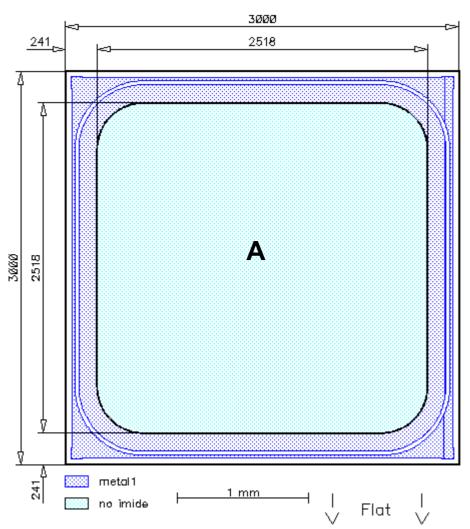
Parameter	Symbol	Conditions	Value			Unit
Falailletei	Symbol	contations	min.	typ.	max.	Unit
Reverse leakage current	I <sub>R</sub>	V <sub>R</sub> =600V			27	μA
Cathode-Anode breakdown Voltage	V <sub>BR</sub>	/ <sub>R</sub> =1.5mA	600			V
Diode forward voltage	V <sub>F</sub>	/ <sub>F</sub> =30A		1.6		V

### **Further Electrical Characteristics**

Switching characteristics and thermal properties are depending strongly on module design and mounting technology and can therefore not be specified for a bare die.



### **Chip Drawing**



Die-Size 3000 um x 3000 um

### A: Anode pad



### Description

AQL 0,65 for visual inspection according to failure catalogue

Electrostatic Discharge Sensitive Device according to MIL-STD 883

### **Revision History**

Version	Subjects (major changes since last revision)	Date

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